

Vishay Siliconix

Automotive N-Channel 100 V (D-S) 175 °C MOSFET

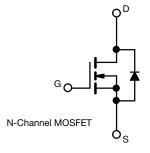
PowerPAK® SO-8L S Top View **Bottom View**

PRODUCT SUMMARY			
V _{DS} (V)	100		
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0119		
I _D (A) ^d	61		
Configuration	Single		

FEATURES

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Q_{gd}/Q_{gs} ratio < 1 optimizes switching characteristics
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ114EP (for detailed order number please see www.vishay.com/doc?79776)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	100	٧	
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current ^d	T _C = 25 °C	L	61		
	T _C = 125 °C	- I _D	35		
Continuous source current (diode conduction) d		I _S	107	Α	
Pulsed drain current ^d		I _{DM}	142		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	30		
Single pulse avalanche energy	L = 0.1 111111	E _{AS}	45	mJ	
Maximum power dissipation	T _C = 25 °C	P _D	117	W	
	T _C = 125 °C	r _D	39		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) ^b			260	C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient ^c	PCB mount a	R_{thJA}	42	°C/W	
Junction-to-case (drain)		R_{thJC}	1.3	G/ VV	

- a. When mounted on 1" square PCB (FR4 material)
 b. See solder profile (www.vishay.com/doc?73257). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Using thermal characterization methods based on JESD51-14
- d. Values based on RthJC and TC of 25 °C. Actual values achievable will be dependent on the thermal characteristics of the complete system



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PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT	
Static							•	
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0$, $I_D = 250 \mu A$		100	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2.5	3.0	3.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = 100 V	-	-	10		
	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 175 °C	-	-	250		
On-state drain current a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	-	-	Α	
Drain-source on-state resistance ^a		V _{GS} = 10 V	I _D = 15 A	-	0.0091	0.0119	Ω	
	R _{DS(on)}	V _{GS} = 10 V	I _D = 15 A, T _J = 125 °C	-	-	0.0240		
		$V_{GS} = 10 \text{ V}$	I _D = 15 A, T _J = 175 °C	-	-	0.0315]	
Forward transconductance b	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 25 \text{ A}$		-	95	-	S	
Dynamic ^b								
Input capacitance	C _{iss}		V _{DS} = 50 V, f = 1 MHz	-	2784	3335	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	187	225		
Reverse transfer capacitance	C _{rss}			-	15	21		
Total gate charge ^c	Q_g			-	38	76		
Gate-source charge c	Q_{gs}	$V_{GS} = 10 \text{ V}$	$V_{GS} = 10 \text{ V}$ $V_{DS} = 20 \text{ V}, I_D = 7.5 \text{ A}$		11	-	nC	
Gate-drain charge ^c	Q_{gd}			-	6	-	•	
Gate resistance	R_g	f = 1 MHz		0.3	1.0	1.7	Ω	
Turn-on delay time ^c	t _{d(on)}				14	21	ns	
Rise time ^c	t _r	V_{DD} = 20 V, R_L = 20 Ω $I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 1 Ω		-	4	8		
Turn-off delay time ^c	t _{d(off)}			-	25	38		
Fall time ^c	t _f			-	4	8		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed current ^a	I _{SM}				-	142	Α	
Forward voltage	V _{SD}	$I_F = 15 \text{ A}, V_{GS} = 0 \text{ V}$		-	-	1.1	V	
Body diode reverse recovery time	t _{rr}	I _F = 10 A, di/dt = 100 A/μs		-	35	70	ns	
Body diode reverse recovery charge	Q _{rr}			-	52	104	nC	
Reverse recovery fall time	t _a			-	29	-	- ns	
Reverse recovery rise time	t _b			-	6	-		
Body diode peak reverse recovery current	I _{RM(REC)}			-	-2.9	-	Α	

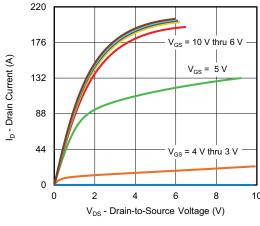
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

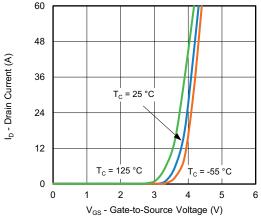
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



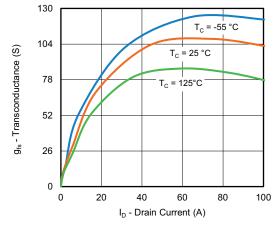
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



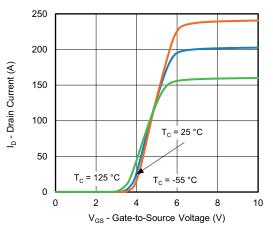
Output Characteristics



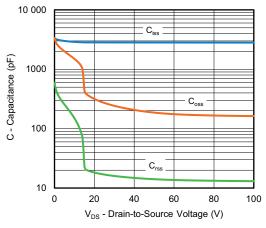
Transfer Characteristics



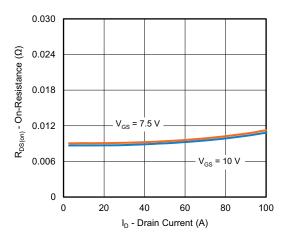
Transconductance



Transfer Characteristics



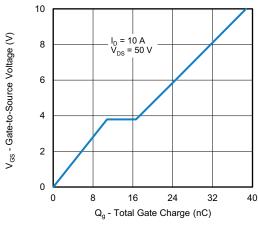
Capacitance



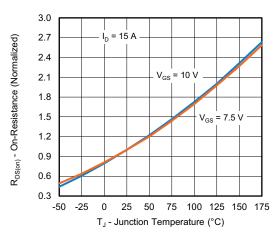
On-Resistance vs. Drain Current



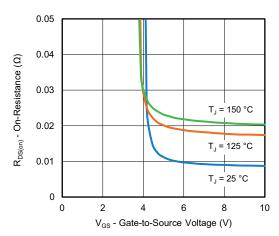
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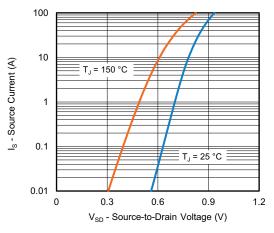


On-Resistance vs. Junction Temperature

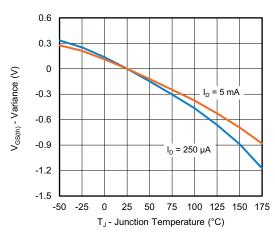


On-Resistance vs. Gate-to Source Voltage

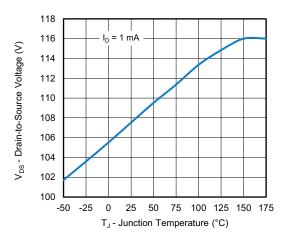
Note a. $V_{GS} > minimum V_{GS}$ at which $R_{DS(on)}$ is specified



Source Drain Diode Forward Voltage



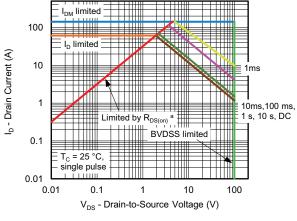
Threshold Voltage



Drain Source Breakdown vs. Junction Temperature

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TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

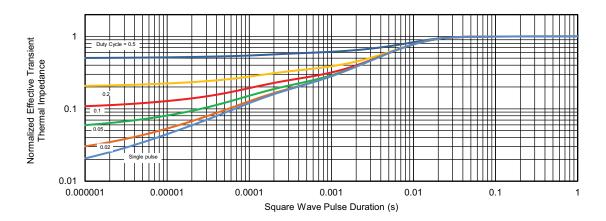


Safe Operating Area

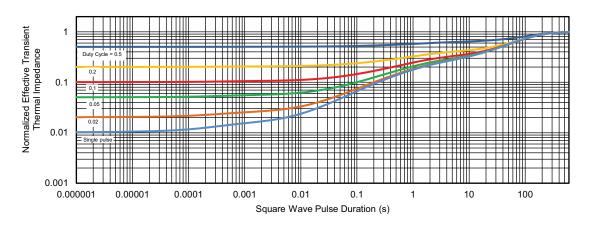
Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified





Normalized Thermal Transient Impedance, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62204.

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